Topological Phases in AB-stacked MoTe\textsubscript{2}/WSe\textsubscript{2}: $\mathbb{Z}_2$ Topological Insulators, Chern Insulators, and Topological Charge Density Waves

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We present a theory on the quantum phase diagram of AB-stacked MoTe\textsubscript{2}/WSe\textsubscript{2} using a self-consistent Hartree-Fock calculation performed in the plane-wave basis, motivated by the observation of topological states in this system. At filling factor $\nu = 2$ (two holes per moiré unit cell), Coulomb interaction can stabilize a $\mathbb{Z}_2$ topological insulator by opening a charge gap. At $\nu = 1$, the interaction induces three classes of competing states, spin density wave states, an in-plane ferromagnetic state, and a valley polarized state, which undergo first-order phase transitions tuned by an out-of-plane displacement field. The valley polarized state becomes a Chern insulator for certain displacement fields. Moreover, we predict a topological charge density wave forming a honeycomb lattice with ferromagnetism at $\nu = 2/3$. Future directions on this versatile system hosting a rich set of quantum phases are discussed.

Introduction. — Topological phases of matter have been among the most active and important research areas in condensed matter physics ever since the experimental discovery of the quantum Hall effect [1] in the presence of strong magnetic fields. The mechanism of the quantum Hall effect, especially the quantization of Hall conductance, has been understood in terms of the Chern number [2, 3]. It was later proposed by Haldane that [4], even without the external magnetic field, a Chern insulator (also known as quantum anomalous Hall insulator) can, in principle, exist and carry a nontrivial Chern number if the time-reversal symmetry $\mathcal{T}$ is broken. When $\mathcal{T}$ symmetry is preserved, however, the Chern number is identically zero. Later, Kane and Mele [5] realized the possibility of another topological state, $\mathbb{Z}_2$ topological insulator (also known as quantum spin Hall insulator), and proposed a model that is composed of two time-reversed-partner copies of the Haldane model with helical edge states protected by the $\mathcal{T}$ symmetry [6]. This work very substantially expanded the scope of topological matter research as it became clear that appropriate band structure engineering can lead to the manifestation of nontrivial topology in real materials with no applied magnetic field. Among the extensive topological theoretical predictions [7–21], only a limited number of systems have so far been studied experimentally manifesting unambiguous topological invariants: Chern insulators have been realized in magnetically doped topological insulator thin films [22, 23], few-layer MnBi\textsubscript{2}Te\textsubscript{4} [24, 25], and graphene-based moiré materials [26–30], and modest transport signatures of the quantum spin Hall effect have been reported in HgTe quantum wells [31], InAs/GaSb quantum wells [32, 33] and monolayer WTe\textsubscript{2} [34, 35].

The recent advent of moiré materials, followed by the discovery of correlated insulators and superconductors in magic-angle twisted bilayer graphene [36, 37], provides vast new opportunities to design different phases of matter, including topological phases discussed above [26–28, 38–48]. It was theoretically proposed [49] that moiré bands in twisted transition metal dichalcogenide heterobilayers can be mapped to the Kane-Mele model [49, 50]. Coulomb repulsion can further drive a rich set of broken symmetry insulating states (e.g., Chern insulators) because the topological moiré bands have narrow bandwidth. This leads to interesting physics involving interplay between band topology and strong correlations. A recent experiment on AB-stacked MoTe\textsubscript{2}/WSe\textsubscript{2} [51] reported well-developed quantum anomalous Hall effect at filling factor $\nu = 1$, and possible evidence for quantum spin Hall effect at $\nu = 2$. This experiment is unprecedented, as it demonstrates experimentally that quantum anomalous Hall and quantum spin Hall effects could be realized in a single system, something never happened before as the two phenomena are quite distinct. It is also surprising, as it utilizes a heterobilayer instead of the homobilayer proposed in Ref. 49 for the manifestation of TMD topology. The surprising rich phenomena observed in MoTe\textsubscript{2}/WSe\textsubscript{2} calls for detailed theoretical studies [52, 53].

In this Letter, we present a topological theoretical study of interacting AB-stacked MoTe\textsubscript{2}/WSe\textsubscript{2}. The single-particle physics is described by a continuum moiré Hamiltonian that incorporates the topmost valence bands from both layers. An out-of-plane displacement field tunes the band offset between the two layers, and drives a topological phase transition for the first moiré valence band. The Coulomb interaction is treated using a self-consistent Hartree-Fock approximation without the bias of projecting it to a few selected moiré bands. At $\nu = 2$, the single-particle band structure predicts a metallic state in the topological regime, but the Coulomb interaction can open up a gap, and therefore, stabilize the $\mathbb{Z}_2$ topological insulator. At $\nu = 1$, we obtain a rich quantum phase diagram that includes three classes of competing phases, spin density wave states, an in-plane ferromagnetic state, and a valley polarized state. The valley polar-
ized state becomes a Chern insulator for a certain range of displacement fields. The above results provide a consistent mean-field description of the experimental observations (along with new predictions) in Ref. 51, which is an important step towards a full understanding of quantum phases in MoTe₂/WSe₂. We predict a topological density wave state at fractional filling factor \( \nu = 2/3 \), and identify the condition for its experimental realization.

**Model.**—We focus on AB-stacked MoTe₂/WSe₂ with an exact 180° twist angle. The moiré superlattices have the \( C_{3v} \) point group symmetry and a moiré period \( a_M = a_b a_i / |a_b - a_i| \), where \((a_b, a_i) = (3.575Å, 3.32Å)\) are the lattice constant of MoTe₂ and WSe₂, respectively. The large lattice constant mismatch makes the moiré superlattices relatively immune to twist angle disorder. As shown in Fig. 1 (a), there are three high symmetry regions in one moiré unit cell, labeled as “MM”, “XX” and “MX”, corresponding to local atomic configurations with \( C_{3z} \) (threefold rotational) symmetry.

The density functional theory calculation [51, 53] of AB-stacked MoTe₂/WSe₂ shows that the valence band edge is contributed mainly by ±\( K \) valley states of MoTe₂, where ±\( K \) refer to corners of the monolayer Brillouin zone. Therefore, we focus on ±\( K \) valleys which are related by the \( T \) symmetry. For valence bands at the two valleys, there are large spin splittings that are both valley and layer dependent, as illustrated in Fig. 1 (b). By retaining the topmost valence bands from each layer, we construct [49, 50, 53] a valley-dependent continuum Hamiltonian as follows

\[
H_\tau = \begin{pmatrix}
\Delta_1(r) & \Delta_\tau,\tau(r) \\
\Delta_{\tau,\tau}(r) & -\frac{\hbar^2}{2m_i} + \Delta_b(r)
\end{pmatrix} + \omega \tau e^{i\tau g_b} \cdot \mathbf{r} + \frac{\omega^2}{\tau} e^{i\tau g_2} \cdot \mathbf{r} + V_{zt},
\]

where \( \tau = \pm 1 \) represents ±\( K \) valleys, and \( \mathbf{K} = \frac{2\pi}{3a_M} (1, 0) \) is a corner of the moiré Brillouin zone. For each valley, the 2 × 2 Hamiltonian hybridizes the bottom layer (b) and top layer (t), where the off-diagonal terms describe the interlayer tunneling \( \Delta_{\tau,\tau} \), and the diagonal terms describe the momentum-shifted kinetic energy with the effective mass \( (m_b, m_t) = (0.65, 0.35)m_e \) (\( m_e \) is the rest electron mass), plus the intralayer potential \( \Delta_b / t \), and a band offset \( V_{zt} \) [Fig. 1(b)]. Our \( H_\tau \) differs from that in Ref. 53 by a gauge transformation.

The periodic potential \( \Delta_b(r) \) is parametrized as

\[
\Delta_b(r) = 2V_b \sum_{j=1,3,5} \cos(g_j \cdot r + \psi_b),
\]

where \( V_b \) and \( \psi_b \) respectively characterize the amplitude and spatial phase of the potential, and \( g_j = \frac{4\pi}{\sqrt{3}a_M} (\sin \frac{\pi(j-1)}{3}, \cos \frac{\pi(j-1)}{3}) \) are the moiré reciprocal lattice vectors in the first shell. We set \( \Delta_1(r) = 0 \), since the low-energy physics only involves the band maximum of WSe₂ [53]. The interlayer tunneling term is

\[
\Delta_{\tau,\tau}(r) = \tau w \left( 1 + \omega r e^{i\tau g_2} + \omega^2 e^{i\tau g_1} \right),
\]

where \( w \) describes the tunneling strength, and \( \omega = e^{i\frac{2\pi}{3}} \) following the \( C_{3z} \) symmetry [53]. The valley dependence of \( \Delta_{\tau,\tau} \) is constrained by \( T \) symmetry. Here \( \Delta_{\tau,\tau} \) couples states with opposite spins, which is symmetry allowed because the heterobilayer breaks the \( z \to -z \) mirror symmetry. For parameters in \( H_\tau \), we take \( \psi_b = -14^\circ \) such that the potential maximum of \( \Delta_b(r) \) is at MM site [53]; \( V_{zt} \) is a parameter that is experimentally controllable by an applied out-of-plane displacement field; \( V_b \) and \( w \) are taken as theoretical parameters that can be adjusted to study different phases. We note that the interlayer tunneling strength \( w \) can be modified by pressure.

The low-energy moiré bands and their topology are tunable by \( V_{zt} \). For the intrinsic band offset \( V_{zt} \) that has a large negative value (\( \sim -110 \) meV) [53], the topmost moiré valence band at each valley mainly derives from the MoTe₂ layer and can be described by a tight-binding model on a triangular lattice, which is topologically trivial. By reducing \( |V_{zt}| \) with an external displacement field, the energy gap between the topmost moiré valence bands derived respectively from MoTe₂ and WSe₂ can close and then reopen. This band inversion enabled by the tunneling term \( \Delta_{\tau,\tau} \) can lead to topological phase transitions. Figure 1(d) presents a topological phase diagram characterized by the valley-contrast Chern numbers \( C_{\pm K} \) of the first moiré valence band in the parameter space of \( (V_{zt}, w) \). For \( V_{zt} \) above the critical value, \( C_{\pm K} \) become
nontrivial with value being ±1. Figure 1(c) plots a representative moiré band structure in the topologically nontrivial regime of Fig. 1(d). Note that there is no overall energy gap that separates the first and second moiré valence bands in Fig. 1(c). The effect of many-body interaction on this gap is crucial as studied in the following.

**Coulomb Interactions.**—The bandwidth of the first moiré valence band is on the order of $\hbar^2 \kappa^2/(2m_b) \approx 47$ meV, while the characteristic Coulomb interaction strength is on the order of $\epsilon^2/(\epsilon a_M) \approx 31$ meV for $a_M \approx 4.7$ nm and dielectric constant $\epsilon = 10$. Therefore, the Coulomb interaction has an energy scale comparable to the bandwidth [Fig. 1(c)], which puts the system in the strongly interacting regime with possible interaction-induced quantum phase transitions. We consider the dual-gate screened Coulomb interaction with the momentum-dependent potential $V(q) = 2\pi\epsilon^2\tan(qd)/\epsilon\eta$, where $d$ is the gate-to-sample distance. We set $d = 5$ nm [51] unless otherwise stated. The dielectric constant $\epsilon$ is of the order of 10-20, and we vary $\epsilon$ to illustrate how physical properties depend on the interaction strength.

We treat the Coulomb interaction using a self-consistent Hartree-Fock (HF) approximation applied to the continuum Hamiltonian in the plane-wave basis (see the Supplemental Material [54] for details). Here, we do not project the Coulomb interaction onto a few low-energy moiré bands, because it is generally not possible to identify a set of bands that are energetically isolated from other bands [Fig. 1(c)]. Our approach allows us to study interaction effects for different parameter regimes in a unified manner. We note that HF theory, although qualitatively reliable, may overestimate the tendency towards ordering, and may not be able to quantitatively capture the global phase diagram. Nevertheless, it is an important and nontrivial question of principle whether the experimental observations can be captured by a mean-field theory.

**$\mathbb{Z}_2$ topological insulator at $\nu = 2$.**—For the single-particle band structure shown in Fig. 1(c), $\nu = 2$ would correspond to a metallic state since there is no overall gap that separates the first and second moiré valence bands. However, after performing the self-consistent HF calculations using the same set of parameters, we find that a true gap develops at $\nu = 2$, as shown in Fig. 2(a). The first moiré valence band at each valley remains topologically nontrivial. Therefore, the $\nu = 2$ insulator belongs to the $\mathbb{Z}_2$ time-reversal invariant topological insulator as the $\mathbb{Z}_2$ topological invariant, defined in our case by $\text{mod}([C_{+K} - C_{-K}]/2,2)$, is nontrivial given $C_{+K} = \pm 1$. This can be viewed as a realization of interaction-induced quantum spin Hall insulator [5].

For generic parameter values, we present the topological phase diagram at $\nu = 2$ calculated using the HF approximation as a function of $\epsilon$ and $V_{z1}$ in Fig. 2(b), where there are two phases, the topologically trivial phase and the $\mathbb{Z}_2$ topological insulator phase, respectively for $V_{z1}$ below and above a critical value. At the critical $V_{z1}$, the charge gap vanishes. The critical $V_{z1}$ increases as $\epsilon$ decreases (Coulomb interaction increases) because a stronger Coulomb interaction opens a larger charge gap.
in the topologically trivial phase, which requires a larger displacement field to close the gap so that the topological phase transition can happen.

**Competing phases at $\nu = 1$.**—We study interaction-induced competing phases at $\nu = 1$ and show the quantum phase diagram in Fig. 3(a), which includes three distinct classes of states, a valley polarized (VP) state, spin density wave (SDW) states, and an in-plane ferromagnetic state ($\text{FM}_x$). We first describe the VP state, where the first moiré valence band at $\pm K$ valleys have unequal occupations. Therefore, the VP state carries a finite out-of-plane spin polarization and spontaneously breaks $T$ symmetry. Figure 3(f) shows a representative band structure calculated using the HF method for the VP state, which has a finite charge gap at $\nu = 1$ and realizes a Chern insulator (ChI) with a quantized Chern number $1$. This gives rise to the VP-ChI phase in Fig. 3(a). The VP state may become topologically trivial for a large negative $V_{z\ell}$. However, such a VP *trivial* phase is absent in Fig. 3(a) because it is energetically unfavorable compared to SDW states for the parameter ranges used in this figure. To the other extreme ($V_{z\ell} \sim 0$), the VP state may become a metallic state that has partial valley polarization, though not energetically favorable compared to $\text{FM}_x$ in Fig. 3(a).

We now turn to SDW and $\text{FM}_x$ phases. The first moiré valence band in the topologically trivial regime of Fig. 1(d) can be described by a single-band tight-binding model on a triangular lattice, which, combined with the Coulomb interaction, realizes a generalized Hubbard model [55]. The single-band Hubbard model on a triangular lattice in the strong interaction limit has the 120° antiferromagnetic Néel ground state [55, 56] at $\nu = 1$, which spontaneously breaks the valley $U(1)$ symmetry in our case and therefore, represents an intervalley-coherent state. The SDW in the 120° Néel state spontaneously breaks the moiré translational symmetry, and has an expanded unit cell with a period $\sqrt{3}a_M$. In Figs. 3(b) to 3(d), we show three types of SDW states, distinguished by their charge and spin patterns in the bottom layer. In SDW1 and SDW2, the holes in the bottom layer are mainly concentrated on MM sites. Both SDW1 and SDW2 have the 120° antiferromagnetic spin texture for holes on MM sites, but they differ by the spin vector chirality [50]. In SDW3, the holes in the bottom layer are redistributed in moiré superlattices such that the hole density on MM and XX sites has comparable magnitude; the corresponding spin texture is shown in Fig. 3(d). In addition, we also consider an $\text{FM}_x$ state, where the spin for holes in the bottom is polarized along an in-plane direction. We perform a self-consistent HF calculation for the SDW and $\text{FM}_x$ states, compare their energies with the VP state, and obtain the phase diagram in Fig. 3(a) as a function of $V_{z\ell}$ and $\epsilon$.

In Fig. 3(e), we show the charge gap as a function of $V_{z\ell}$ at a fixed $\epsilon$. As $V_{z\ell}$ increases from a large negative value towards 0, there is a first-order phase transition between the topologically trivial SDW phase and the topological VP ChI phase. Because the first-order phase transition breaks adiabatic continuity, the charge gap does not need to vanish at the transition point, and there can be a discontinuous jump in the gap. In contrast, the experimental charge gap [51] evolves *continuously* across the transition from a Mott insulator to a Chern insulator at $\nu = 1$, which could be due to disorder effects [57].

**Topological charge density waves at $\nu = 2/3$.**—Correlated insulators can develop not only at integer $\nu$, but also at fractional $\nu$, as demonstrated experimentally in Refs. 58–62. Here we focus on $\nu = 2/3$, where the Coulomb interaction can induce a charge density wave (CDW) state that forms a honeycomb lattice [63]. The enlarged unit cell has a period $\sqrt{3}a_M$ and contains three MM sites, but only two out of the three are occupied by holes of the bottom layer, which, therefore, leads to an effective honeycomb lattice. We theoretically find that the CDW state at $\nu = 2/3$ is sensitive to the long-range part of the Coulomb interaction, and can be energetically stabilized for $d = 15$ nm rather than $d = 5$ nm, where $d$ is the sample-to-gate distance and controls the effective range of the Coulomb interaction.

On the effective honeycomb lattice, there can be two types of spin ordering [63]: (1) antiferromagnetic ($\text{AF}_z$) order and (2) ferromagnetic ($\text{FM}_z$) order, where spin polarization axis is out of plane for both cases as illustrated respectively in Figs. 4(b) and 4(c). Here the $\text{FM}_z$ state is also valley polarized. We perform self-consistent HF cal-

![FIG. 4](image-url)

(a) Interaction-induced phase diagram at $\nu = 2/3$ with $\epsilon = 17$, $w=12$ meV, and $V_b=7$ meV. Note that the sample-to-gate distance $d$ has changed from 5 nm to 15 nm compared to other figures. The two competing phases are $\text{AF}_z$-HC and $\text{FM}_z$-HC, which respectively have $\text{AF}_z$ and $\text{FM}_z$ spin ordering on a generalized Wigner crystal with honeycomb lattice on the bottom layer. (b) and (c) The spatial variation of the $z$ component spin $s_z$ on the bottom layer for $\text{AF}_z$-HC and $\text{FM}_z$-HC. The red dashed lines mark the emergent honeycomb lattice with a period of $\sqrt{3}a_M$ and vertices on MM sites.
culations respectively for the AF\textsubscript{z} honeycomb (AF\textsubscript{z}-HC) state and the FM\textsubscript{z} honeycomb (FM\textsubscript{z}-HC) state. Their energy competition gives rise to the $\nu = 2/3$ phase diagram in Fig. 4(a), where AF\textsubscript{z}-HC and FM\textsubscript{z}-HC states are favorable respectively for $V_{\text{at}}$ below and above a critical value. Remarkably, when FM\textsubscript{z}-HC state becomes energetically favorable, it is also topologically nontrivial with a quantized Chern number 1. Therefore, there can be a getically favorable, it is also topologically nontrivial with $\nu = 1$, i.e., band inversion induced by $V_{\text{at}}$.

**Conclusion.** — Our self-consistent theoretical results provide a reasonable qualitative understanding for the field-induced topological states in Ref. 51. The theory sets up a general framework to study topological interaction effects in transition metal dichalcogenide moiré system, and can be readily applied to study a variety of interaction-induced symmetry breaking phases [50, 58, 63–68]. For AB-stacked MoTe\textsubscript{2}/WSe\textsubscript{2}, many future directions can be explored in both theory and experiment. The $\nu = 1$ Chern insulator has spontaneous VP, but does not break any continuous symmetry. It is an Ising-type ordering with a finite Curie temperature, which could be theoretically estimated by studying the valley magnon and domain fluctuations [69]. This VP state can result in interesting optical phenomena, for example, Faraday and Kerr rotations [70]. The multiple distinct quantum phases (SDW, ChI, and $Z_2$ topological insulators) that emerge in a single system can be used as building blocks to design new quantum phases on demand. For example, by introducing proximitized superconductivity, an interface between the $\nu = 1$ SDW state and the $\nu = 2$ $Z_2$ topological insulator could host Majorana zero modes.

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